

## TB0640H thru TB4000H

# SURFACE MOUNT THYRISTOR SURGE PROTECTIVE DEVICE

#### **Bi-Directional**

VDRM - **58 to 360** Volts IPP - **100** Amperes

SMB

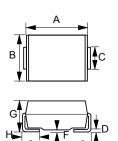
#### **FEATURES**

- Oxide Glass Passivated Junction
- Bidirectional protection in a single device
- Surge capabilities up to 100A @ 10/1000us or 400 @ 8/20us
- High off state Impedance and low on state voltage
- Plastic material has UL flammability classification 94V-0

#### **MECHANICAL DATA**

• Case : Molded plastic

Polarity: Denotes none cathode bandWeight: 0.003 ounces, 0.093 grams



SMB				
MIN.	MAX.			
4.06	4.57			
3.30	3.94			
1.96	2.21			
0.15	0.31			
5.21	5.59			
0.05	0.20			
2.01	2.62			
0.76	1.52			
All Dimensions in millimeter				
	MIN. 4.06 3.30 1.96 0.15 5.21 0.05 2.01 0.76			

#### **MAXIMUM RATINGS**

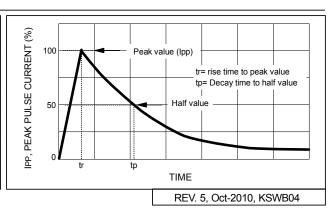
CHARACTERISTICS	SYMBOL	VALUE	UNIT
Non-repetitive peak impulse current @ 10/1000us	IPP	100	Α
Non-repetitive peak On-state current @ 8.3ms (one half cycle)	ITSM	50	Α
Junction temperature range	TJ	-40 to +150	°C
storage temperature range	TSTG	-55 to +150	°C

#### THERMAL RESISTANCE

CHARACTERISTICS	SYMBOL	VALUE	UNIT
Junction to leads	Rth(J-L)	20	°C <b>/W</b>
Junction to ambient on print circuit (on recommended pad layout)	Rth(J-A)	100	°C <b>/W</b>
Typical positive temperature coefficient for brekdown voltage	△VBR/△TJ	0.1	%/°C

#### **MAXIMUM RATED SURGE WAVEFORM**

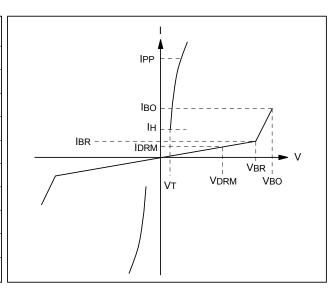
WAVEFORM	STANDARD	IPP (A)
2/10 us	GR-1089-CORE	500
8/20 us	IEC 61000-4-5	400
10/160 us	FCC Part 68	250
10/560 us	FCC Part 68	200
10/700 us	ITU-T K20/K21	160
10/1000 us	GR-1089-CORE	100





PARAMETER	RATED REPETITIVE OFF-STATE VOLTAGE	OFF-STATE LEAKAGE CURRENT @ VDRM	BREAKOVER VOLTAGE	ON-STATE VOLTAGE @ IT=1.0A		KOVER RENT		DING RENT	OFF-STATE CAPACITANCE
SYMBOL	VDRM	IDRM	VBO	VT	IBO		IBO IH		Со
UNITS	Volts	uA	Volts	Volts	mA		mA mA		pF
LIMIT	Max	Max	Max	Max	Min	Max	Min	Max	Тур
TB0640H	58	5	77	3.5	50	800	150	800	200
TB0720H	65	5	88	3.5	50	800	150	800	200
ТВ0900Н	75	5	98	3.5	50	800	150	800	200
TB1100H	90	5	130	3.5	50	800	150	800	120
TB1300H	120	5	160	3.5	50	800	150	800	120
TB1500H	140	5	180	3.5	50	800	150	800	120
TB1800H	170	5	220	3.5	50	800	150	800	120
TB2300H	190	5	265	3.5	50	800	150	800	80
TB2600H	220	5	300	3.5	50	800	150	800	80
TB3100H	275	5	350	3.5	50	800	150	800	80
TB3500H	320	5	400	3.5	50	800	150	800	80
TB4000H	360	5	450	3.5	50	800	150	800	80

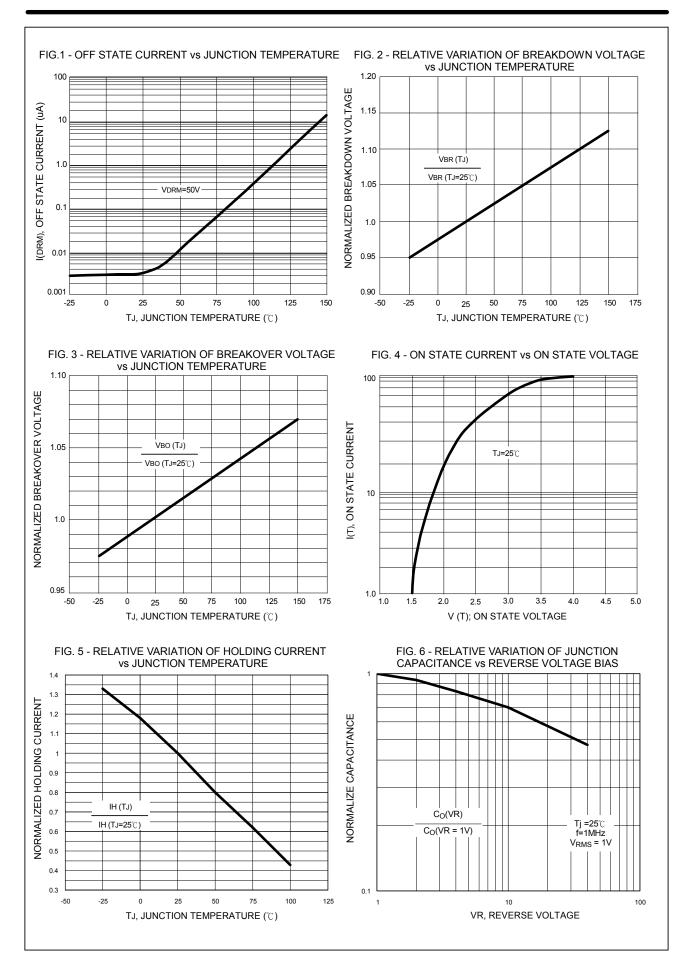
SYMBOL	PARAMETER			
VDRM	Stand-off Voltage			
IDRM	Leakage current at stand-off voltage			
VBR	Breakdown voltage			
IBR	Breakdown current			
Vво	Breakover voltage			
IBO	Breakover current			
lH	Holding current	Note: 1		
VT	On state voltage			
IPP	Peak pulse current			
Со	Off state capacitance	Note: 2		



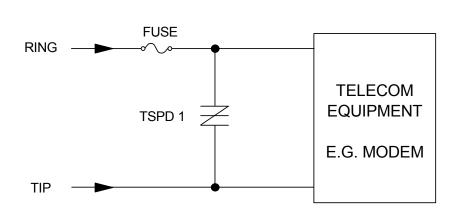
NOTES: 1. IH > (VL/RL) If this criterion is not obeyed, the TSPD Triggers but does not return correctly to high-resistance state. The Surge recovery time does not exceed 30ms.

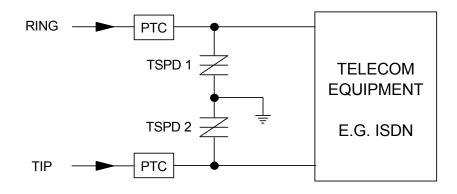
2. Off-state capacitance measured at f=1.0MHz; 1.0VRMS signal; VR=2VDC bias.

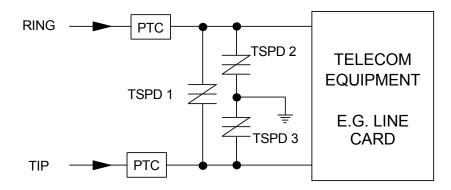












The PTC (Positive Temperature Coefficient) is an overcurrent protection device



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